

# SAA 154 ... SAA 160



## Surface mount diode

## Fast Avalanche Diodes

### SAA 154 ... SAA 160

Forward Current: 1 A

Reverse Voltage: 50 to 1000 V

### Features

- Max. solder temperature: 260°C
- Plastic material has UL classification 94V-0

### Mechanical Data

- Plastic case: Melf / DO-213AB
- Weight approx.: 0,12 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 5000 pieces per reel

1) Max. temperature of the terminals  $T_T = 100\text{ °C}$

2)  $I_F = 1\text{ A}$ ,  $T_J = 25\text{ °C}$

3)  $T_A = 25\text{ °C}$

4) Mounted on P.C. board with 50 mm<sup>2</sup> copper pads at each terminal

Type	Polarity color band	Repetitive peak reverse voltage $V_{RRM}$ V	Surge peak reverse voltage $V_{RSM}$ V	Maximum forward voltage $T_J = 25\text{ °C}$ $I_F = 1\text{ A}$ $V_F^{(2)}$ V	Maximum reverse recovery time $I_F = 0,5\text{ A}$ $I_R = 1\text{ A}$ $I_{RR} = 0,25\text{ A}$ $t_{rr}$ ns
SAA 154	-	50	50	1,3	300
SAA 155	-	100	100	1,3	300
SAA 156	-	200	200	1,3	300
SAA 157	-	400	400	1,3	300
SAA 158	-	600	600	1,3	300
SAA 159	-	800	800	1,3	300
SAA 160	-	1000	1000	1,3	300

### Absolute Maximum Ratings

$T_A = 25\text{ °C}$ , unless otherwise specified

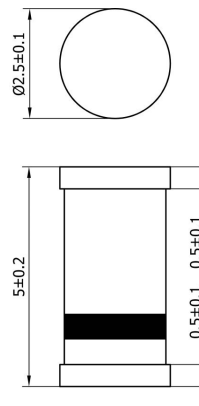
Symbol	Conditions	Values	Units
$I_{FAV}$	Max. averaged fwd. current, R-load, $T_T = 100\text{ °C}$ <sup>1)</sup>	1	A
$I_{FRM}$	Repetitive peak forward current $f > 15\text{ Hz}$ <sup>1)</sup>	10	A
$I_{FSM}$	Peak fwd. surge current 50 Hz half sinus-wave <sup>3)</sup>	35	A
$I^2t$	Rating for fusing, $t < 10\text{ ms}$ <sup>3)</sup>	6	A <sup>2</sup> s
$R_{thA}$	Max. thermal resistance junction to ambient <sup>4)</sup>	45	K/W
$R_{thT}$	Max. thermal resistance junction to terminals	15	K/W
$T_J$	Operating junction temperature	- 50 ... + 175	°C
$T_s$	Storage temperature	- 50 ... + 175	°C

### Characteristics

$T_A = 25\text{ °C}$ , unless otherwise specified

Symbol	Conditions	Values	Units
$I_R$	Maximum leakage current, $T_J = 25\text{ °C}$ ; $V_R = V_{RRM}$ $T_J = \text{°C}$ ; $V_R = V_{RRM}$	<1,5	µA
$C_J$	Typical junction capacitance (at MHz and applied reverse voltage of V)	-	pF
$Q_{rr}$	Reverse recovery charge ( $U_R = V$ ; $I_F = A$ ; $dI_F/dt = A/ms$ )	-	µC
$E_{RSM}$	Non repetitive peak reverse avalanche energy ( $L = 1000\text{ mH}$ ; $T_J = 25\text{ °C}$ ; inductive load switched off)	20	mJ

Dimensions in mm



case: Melf / DO-213AB

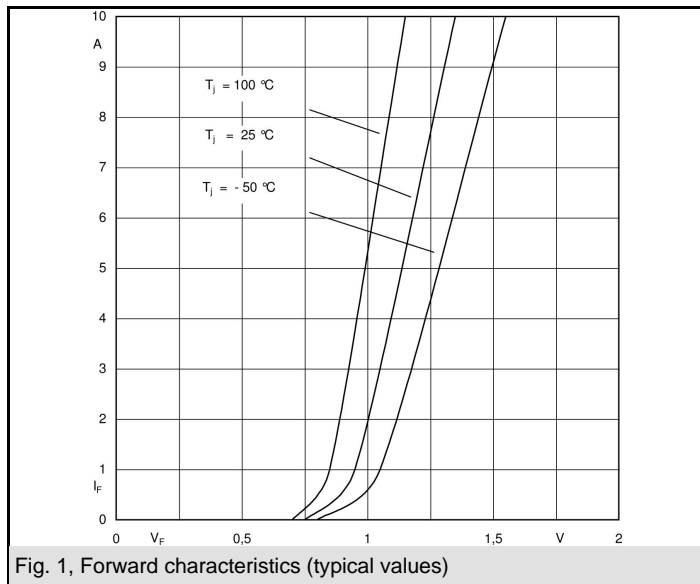


Fig. 1, Forward characteristics (typical values)

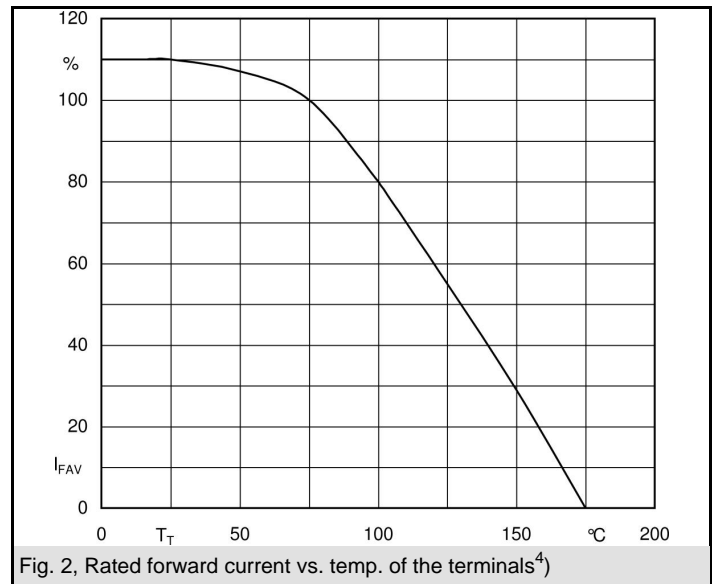


Fig. 2, Rated forward current vs. temp. of the terminals<sup>4)</sup>